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BLP05H6150XR; BLP05H6150XRG

Power LDMOS transistor

AMPLEON

Rev. 4 — 21 September 2016

Product data sheet

1. Product profile

1.1 General description

A 150 W extremely rugged LDMOS power transistor for broadcast and industrial applications in the HF to 600 MHz band.

Table 1. Application information

Test signal	f	V _{DS}	P_L	G _p	η_D	ACPR
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)
pulsed RF	108	50	150	27	75	-
CW	1.8 to 30	50	100	29	60	-
	135	50	150	26	73	-
	174 to 230	50	150	22	67	-
DVB-T	174 to 230	50	25	23	29	-36

1.2 Features and benefits

- Easy power control
- Integrated double sided ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (HF to 600 MHz)
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

- Industrial, scientific and medical applications
- Broadcast transmitter applications

2. Pinning information

Table 2. Pinning

4 3	7
	1 L-1 L+1
	1 1 1 1 1 1 1 1 1 1
	
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pin 1 index	7 - 5
[1]	2
1 2	3
	aaa-003574
4 3	■
pin 1 index	
[1] 1 2	2 —
	' 3
	aaa-003574
	1 2 4 3 pin 1 index

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package	Package				
	Name	Description	Version			
BLP05H6150XR	HSOP4F	plastic, heatsink small outline package; 4 leads (flat)	SOT1223-2			
BLP05H6150XRG	HSOP4F	plastic, heatsink small outline package; 4 leads	SOT1224-2			

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	135	V
V_{GS}	gate-source voltage		-6	+11	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature	[1]	-	225	°C

^[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

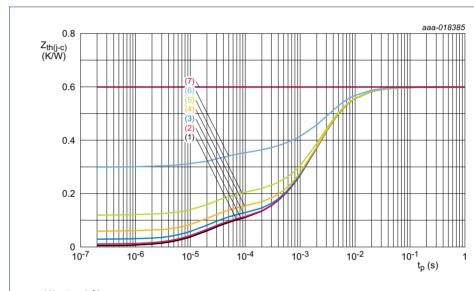
BLP05H6150XR_H6150XRG

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions		Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	T _j = 125 °C	[1][2]	0.6	K/W
Z _{th(j-c)}	transient thermal impedance from junction to case	T_j = 150 °C; t_p = 100 μs; δ = 20 %	[3]	0.21	K/W

- [1] T_i is the junction temperature.
- [2] $R_{th(j-c)}$ is measured under RF conditions.
- [3] See Figure 1.



- (1) $\delta = 1 \%$
- (2) $\delta = 2 \%$
- (3) $\delta = 5 \%$
- (4) $\delta = 10 \%$
- (5) $\delta = 20 \%$
- (6) $\delta = 50 \%$
- (7) $\delta = 100 \% (DC)$

Fig 1. Transient thermal impedance from junction to case as a function of pulse duration

6. Characteristics

Table 6. DC characteristics

 $T_j = 25$ °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.5 \text{ mA}$	135	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V_{DS} = 10 V; I_{D} = 50 mA	1.25	1.8	2.25	V
V_{GSq}	gate-source quiescent voltage	V_{DS} = 50 V; I_{D} = 20 mA	-	1.7	-	V

BLP05H6150XR_H6150XRG

Table 6. DC characteristics ...continued

 T_i = 25 °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 50 V	-	-	1.4	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	7.2	-	Α
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	140	nA
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 1.75 \text{ A}$	-	0.8	-	Ω

Table 7. AC characteristics

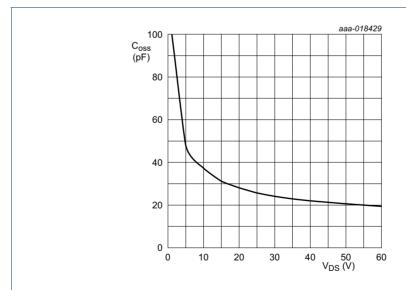
 T_i = 25 °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C _{rs}	feedback capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	0.5	-	pF
C _{iss}	input capacitance	V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz	-	60	-	pF
Coss	output capacitance	V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz	-	21	-	pF

Table 8. RF characteristics

Test signal: pulsed RF; t_p = 100 μ s; δ = 20 %; f = 108 MHz; RF performance at V_{DS} = 50 V; I_{Dq} = 100 mA; T_{case} = 25 $^{\circ}$ C; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	P _L = 150 W	25.5	27	-	dB
RLin	input return loss	P _L = 150 W	-	-8	-	dB
η_{D}	drain efficiency	P _L = 150 W	73	75	-	%



 $V_{GS} = 0 V$; f = 1 MHz.

Fig 2. Output capacitance as a function of drain-source voltage; typical values per section

7. Test information

7.1 Ruggedness in class-AB operation

The BLP05H6150XR and BLP05H6150XRG are capable of withstanding a load mismatch corresponding to VSWR > 65 : 1 through all phases under the following conditions: $V_{DS} = 50 \text{ V}$; $I_{Dq} = 40 \text{ mA}$; $P_L = 150 \text{ W}$ pulsed; f = 108 MHz.

7.2 Impedance information

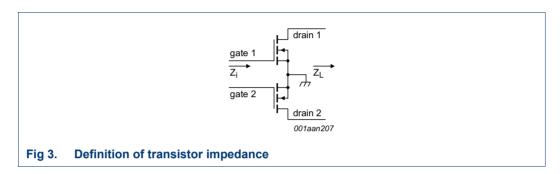


Table 9. Typical push-pull impedance

Simulated Z_i and Z_L device impedance; impedance info at V_{DS} = 50 V and P_L = 150 W.

f	Z _i	Z_L
(MHz)	(Ω)	(Ω)
108	32 – j99	25 + j6.0

7.3 UIS avalanche energy

Table 10. Typical avalanche data per section

 T_{amb} = 25 °C; typical test data; test jig without water cooling.

las	E _{AS}
(A)	(J)
4	0.38
5	0.26
6	0.18

For information see application note AN10273.

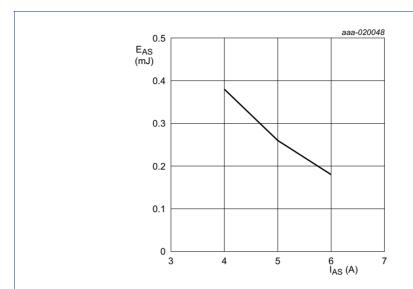
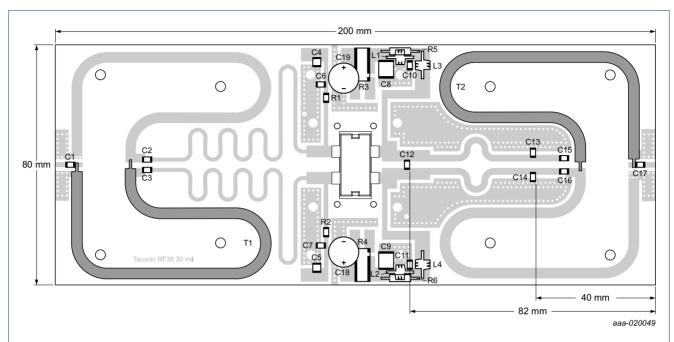


Fig 4. Non-repetitive avalanche energy as a function of single pulse avalanche current; typical values

7.4 Test circuit



Printed-Circuit Board (PCB): RF-35; ϵ_r = 3.5 F/m; thickness = 0.765 mm; thickness copper plating = 35 μ m. See <u>Table 11</u> for a list of components.

Fig 5. Component layout for class-AB production test circuit

Table 11. List of components

For test circuit see Figure 5.

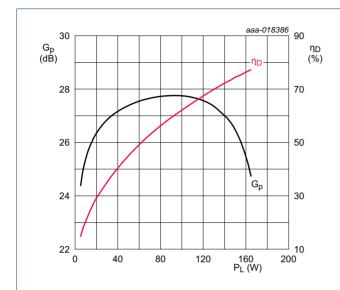
Component	Description	Value		Remarks
C1	multilayer ceramic chip capacitor	68 pF	[1]	
C2, C3	multilayer ceramic chip capacitor	220 pF	[1]	
C4, C5	multilayer ceramic chip capacitor	4.7 μF, 50 V		Kemet: C1210X475K5RAC-T4
C6, C7	multilayer ceramic chip capacitor	750 pF	[1]	
C8, C9	multilayer ceramic chip capacitor	4.7 μF, 100 V		TDK: C5750X7R2A475KT
C10, C11	multilayer ceramic chip capacitor	750 pF	[1]	
C12	multilayer ceramic chip capacitor	10 pF	[1]	
C13, C14	multilayer ceramic chip capacitor	43 pF	[1]	
C15, C16	multilayer ceramic chip capacitor	390 pF	[1]	
C17	multilayer ceramic chip capacitor	47 pF	[1]	
C18,C19	electrolytic capacitor	2200 μF, 64 V		
L1, L2	wire inductor	5 turns, D = 3 mm, 1 mm copper wire		
L3, L4	wire inductor	6 turns, D = 3 mm, 1 mm copper wire		
R1, R2	resistor	4.7 kΩ		SMD 1206
R3, R4	shunt resistor	0.01 Ω		Ohmite: FC4L110R010FER
R5, R6	metal film resistor	10 Ω, 0.6 W		
T1, T2	semi rigid coax	50Ω , length = 160 mm		EZ Form: EZ-141-AL-TP-M17

[1] American Technical Ceramics type 100B or capacitor of same quality.

7.5 Graphical data

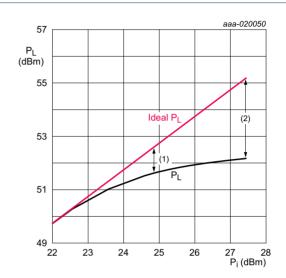
The following figures are measured in a class-AB production test circuit.

7.5.1 1-Tone CW pulsed



 V_{DS} = 50 V; I_{Dq} = 40 mA; f = 108 MHz; t_p = 100 $\mu s;$ δ = 20 %.

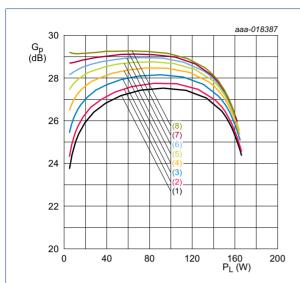
Fig 6. Power gain and drain efficiency as function of output power; typical values



 V_{DS} = 50 V; I_{Dq} = 40 mA; f = 108 MHz; t_p = 100 $\mu s;$ δ = 20 %.

- (1) $P_{L(1dB)} = 51.6 \text{ dBm } (146 \text{ W})$
- (2) $P_{L(3dB)} = 52.2 \text{ dBm } (165 \text{ W})$

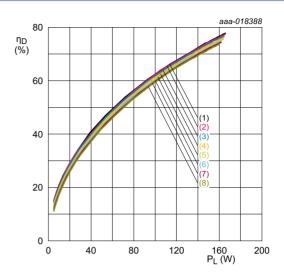
Fig 7. Output power as a function of input power; typical values



 V_{DS} = 50 V; f = 108 MHz; t_p = 100 μ s; δ = 20 %.

- (1) $I_{Dq} = 20 \text{ mA}$
- (2) $I_{Dq} = 40 \text{ mA}$
- (3) $I_{Dq} = 100 \text{ mA}$
- (4) $I_{Dq} = 200 \text{ mA}$
- (5) $I_{Dq} = 300 \text{ mA}$
- (6) $I_{Dq} = 400 \text{ mA}$
- (7) $I_{Dq} = 500 \text{ mA}$
- (8) $I_{Dq} = 600 \text{ mA}$

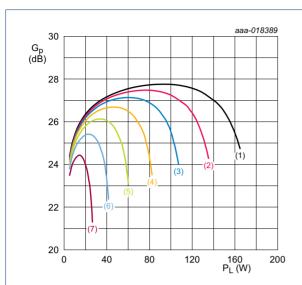
Fig 8. Power gain as a function of output power; typical values



 V_{DS} = 50 V; f = 108 MHz; t_p = 100 μ s; δ = 20 %.

- (1) $I_{Dq} = 20 \text{ mA}$
- (2) $I_{Dq} = 40 \text{ mA}$
- (3) $I_{Dq} = 100 \text{ mA}$
- (4) $I_{Dq} = 200 \text{ mA}$
- (5) $I_{Dq} = 300 \text{ mA}$
- (6) $I_{Dq} = 400 \text{ mA}$
- (7) $I_{Dq} = 500 \text{ mA}$
- (8) $I_{Dq} = 600 \text{ mA}$

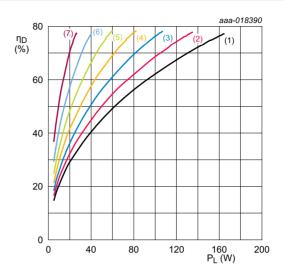
Fig 9. Drain efficiency as a function of output power; typical values



 I_{Da} = 40 mA; f = 108 MHz; t_{o} = 100 μ s; δ = 20 %.

- (1) $V_{DS} = 50 \text{ V}$
- (2) $V_{DS} = 45 \text{ V}$
- (3) $V_{DS} = 40 \text{ V}$
- (4) $V_{DS} = 35 V$
- (5) $V_{DS} = 30 \text{ V}$
- (6) $V_{DS} = 25 \text{ V}$
- (7) $V_{DS} = 20 \text{ V}$

Fig 10. Power gain as a function of output power; typical values



 I_{Dq} = 40 mA; f = 108 MHz; t_p = 100 $\mu s;$ δ = 20 %.

- (1) $V_{DS} = 50 \text{ V}$
- (2) $V_{DS} = 45 \text{ V}$
- (3) $V_{DS} = 40 \text{ V}$
- (4) $V_{DS} = 35 V$
- (5) $V_{DS} = 30 V$
- (6) $V_{DS} = 25 V$
- (7) $V_{DS} = 20 \text{ V}$

Fig 11. Drain efficiency as a function of output power; typical values

8. Package outline

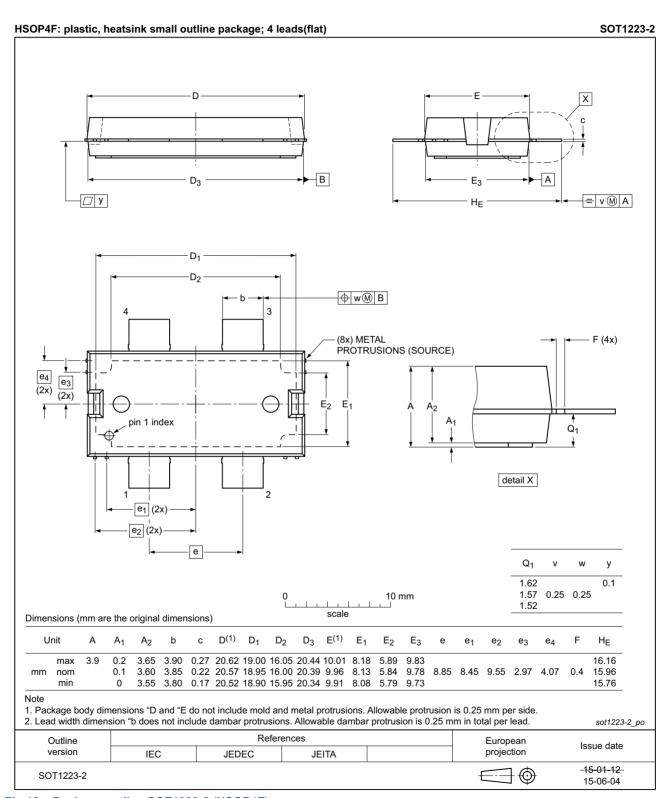


Fig 12. Package outline SOT1223-2 (HSOP4F)

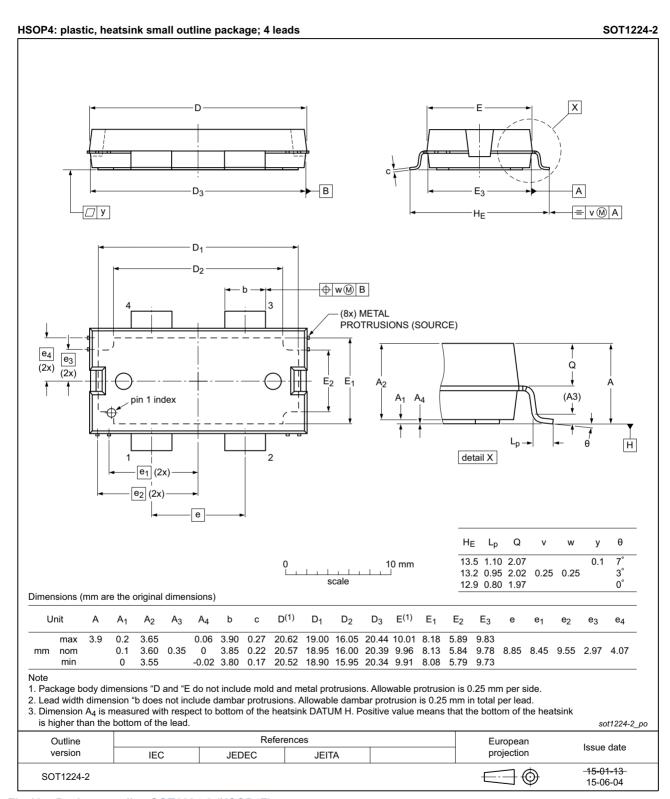


Fig 13. Package outline SOT1224-2 (HSOP4F)

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

10. Abbreviations

Table 12. Abbreviations

Acronym	Description
CW	Continuous Wave
DVB-T	Digital Video Broadcast - Terrestrial
ESD	ElectroStatic Discharge
HF	High Frequency
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MTF	Median Time to Failure
SMD	Surface Mounted Device
UIS	Unclamped Inductive Switching
VSWR	Voltage Standing-Wave Ratio

11. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLP05H6150XR_H6150XRG v.4	20160921	Product data sheet	-	BLP05H6150XR v.3	
Modifications	 The document now describes both the straight lead and gull-wing versions of this product: BLP05H6150XR and BLP05H6150XRG respectively 				
	Table 2 on page 2: added BLP05H6150XRG data				
	Table 3 on p	oage 2: added BLP05H61	50XRG data		
	Section 7.1 on page 5: added BLP05H6150XRG				
	• Figure 13 on page 12: added figure SOT1224-2				
BLP05H6150XR v.3	20160108	Product data sheet	-	BLP05H6150XR#2	
BLP05H6150XR#2	20150901	Objective data sheet	-	BLP05H6150XR v.1	
BLP05H6150XR v.1	20150518	Objective data sheet	-	-	

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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Power LDMOS transistor

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Power LDMOS transistor

14. Contents

1	Product profile
1.1	General description 1
1.2	Features and benefits
1.3	Applications
2	Pinning information 2
3	Ordering information
4	Limiting values 2
5	Thermal characteristics 3
6	Characteristics
7	Test information 5
7.1	Ruggedness in class-AB operation 5
7.2	Impedance information 5
7.3	UIS avalanche energy 5
7.4	Test circuit
7.5	Graphical data 8
7.5.1	1-Tone CW pulsed 8
8	Package outline
9	Handling information
10	Abbreviations
11	Revision history
12	Legal information 14
12.1	Data sheet status
12.2	Definitions
12.3	Disclaimers
12.4	Licenses
12.5	Trademarks
13	Contact information
14	Contents

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